

General Description

The MY6N03A use Trench Power MV MOSFET technology, have Excellent package for heat dissipation, use High density cell design for low $R_{DS(ON)}$

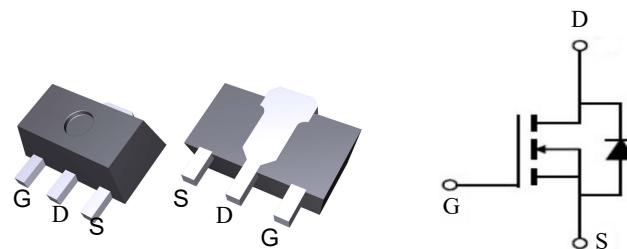


Features

V_{DSS}	30	V
I_D	6	A
$R_{DS(ON)}(\text{at } V_{GS} = 4.5V)$	<28	$m\Omega$
$R_{DS(ON)}(\text{at } V_{GS} = 2.5V)$	<40	$m\Omega$

Application

- DC-DC Converters
- Power management functions



Package Marking and Ordering Information

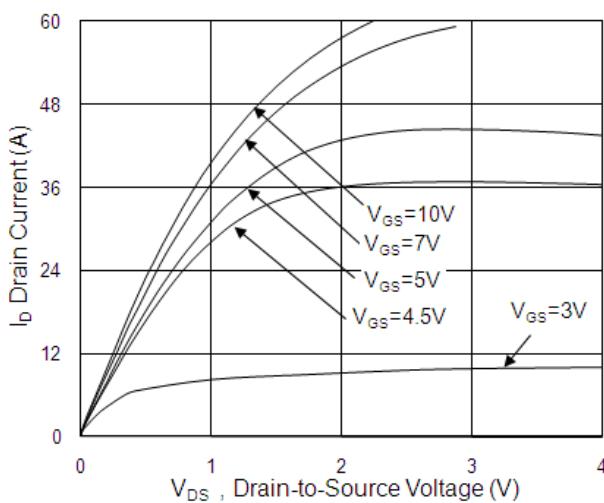
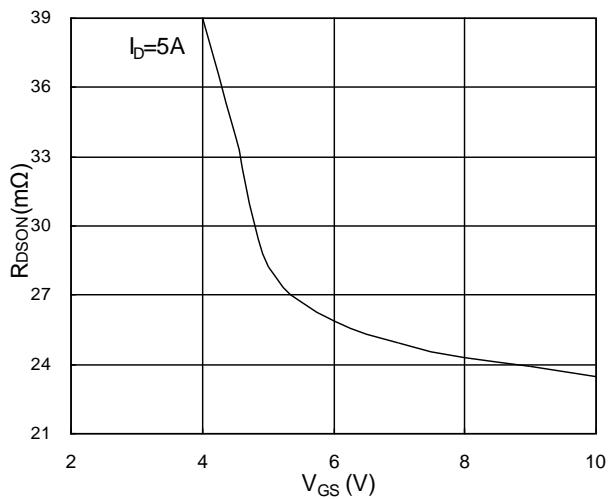
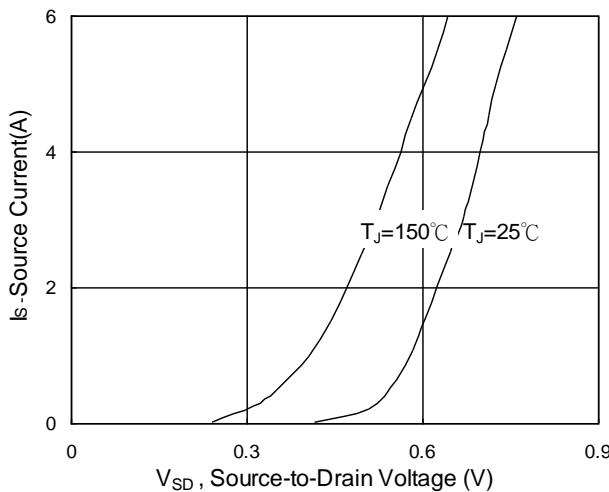
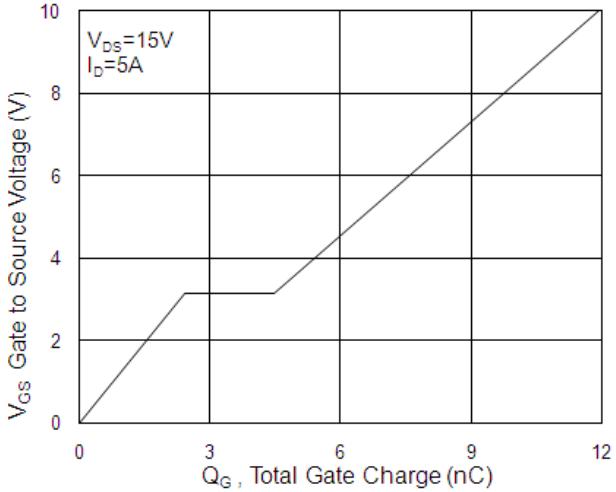
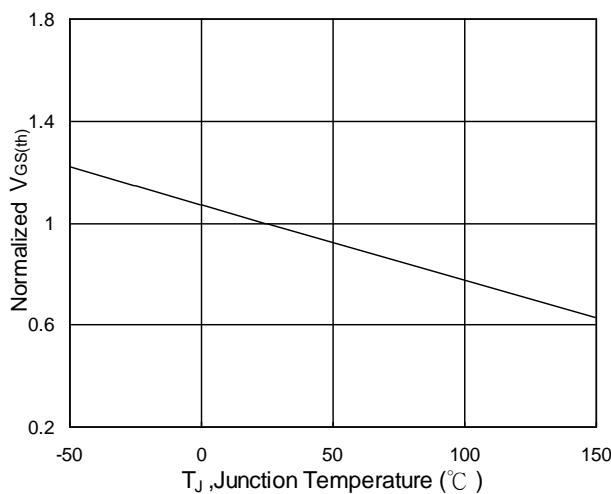
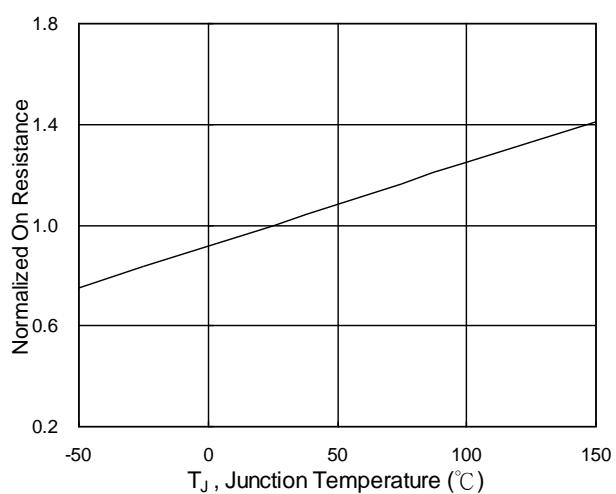
Product ID	Pack	Marking	Qty(PCS)
MY6N03A	SOT-89	6N03A	1000

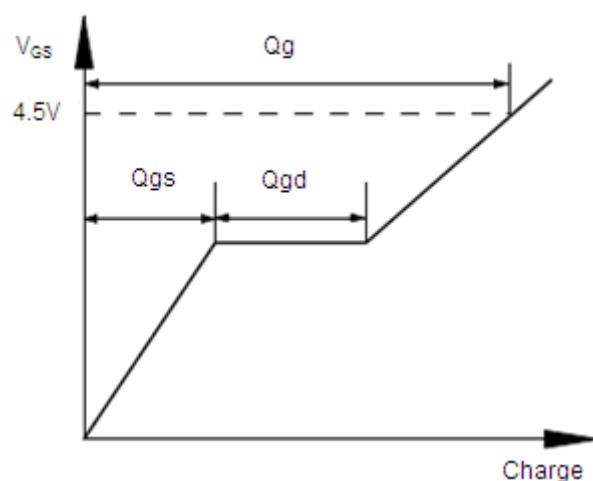
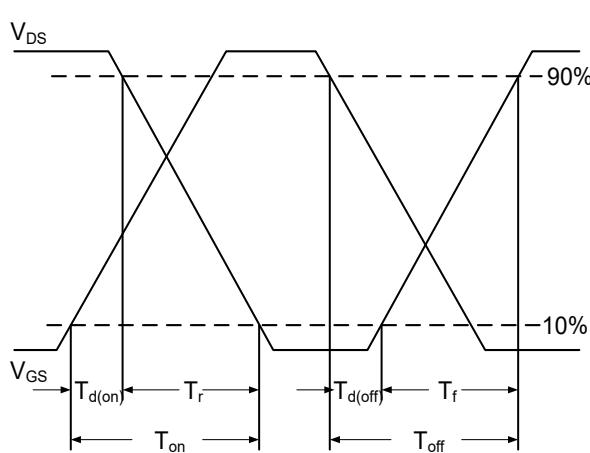
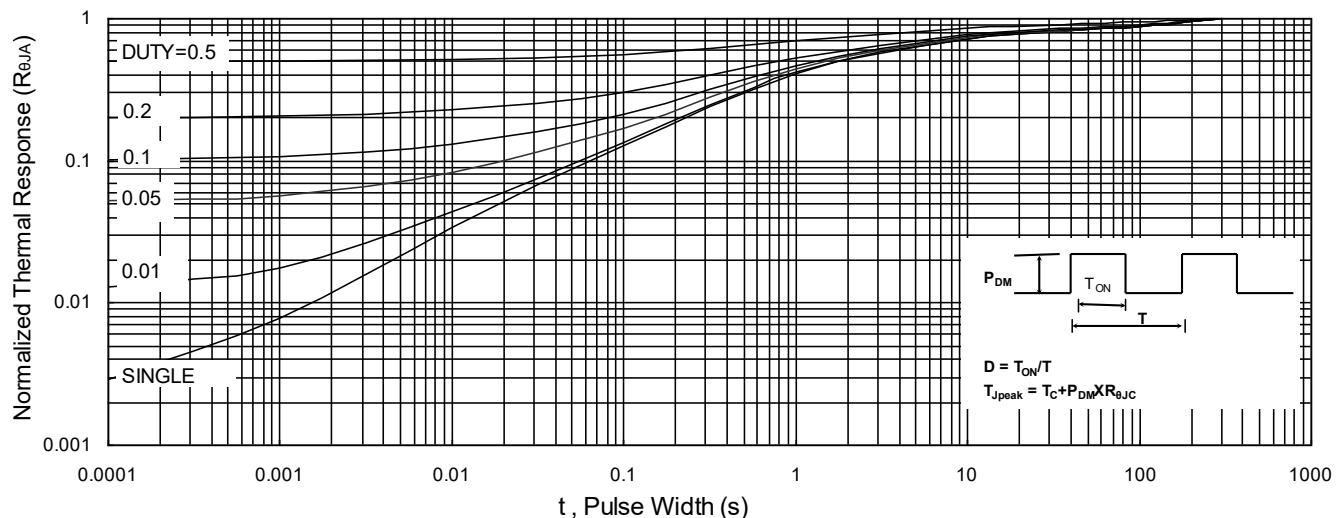
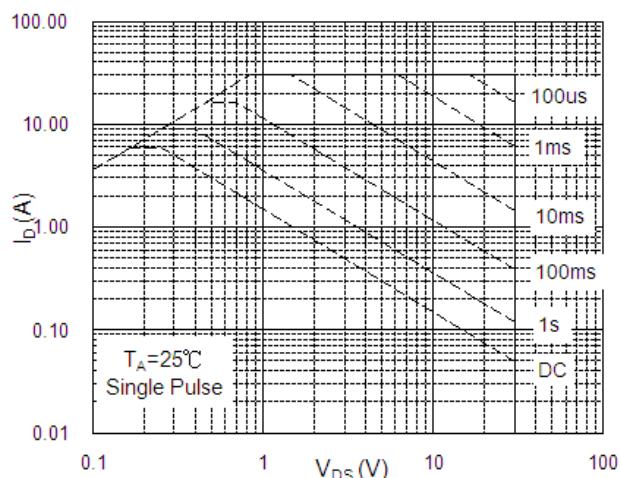
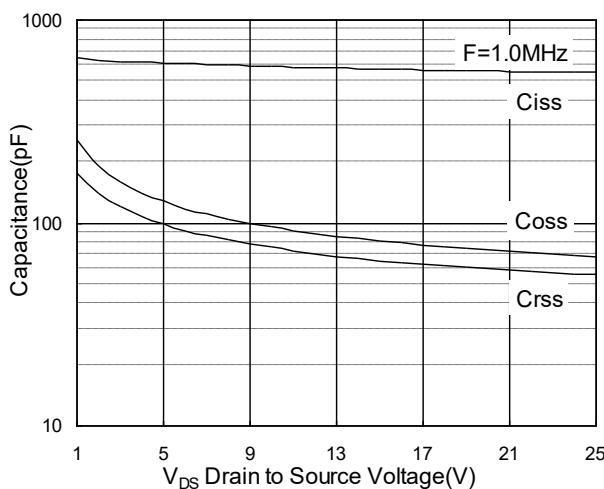
Absolute Maximum Ratings ($T_c=25^\circ C$ unless otherwise noted)

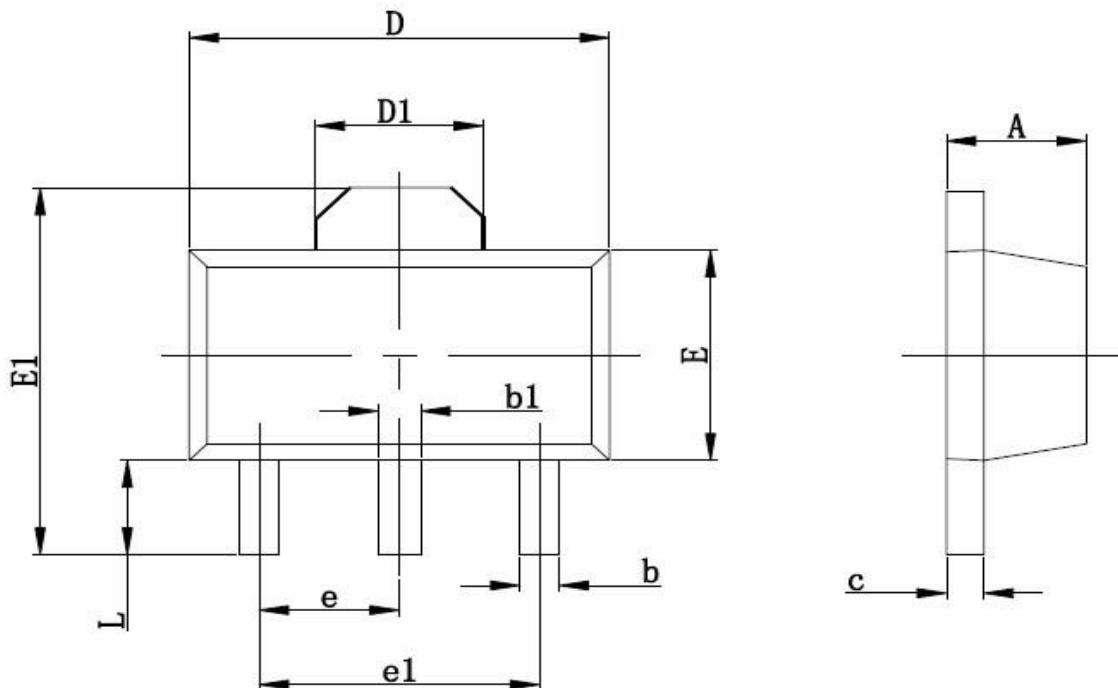
Parameter	Symbol	Limit	Unit
Drain-source Voltage	V_{DS}	30V	V
Gate-source Voltage	V_{GS}	± 12	V
Drain Current	I_D	6	A
Pulsed Drain Current A	I_{DM}	12	A
Avalanche energy B	E_{AS}	8	mJ
Total Power Dissipation C	PD	1.2	W
TA=25°C		0.8	
TA=70°C			
Junction and Storage Temperature Range	T_J, T_{STG}	-55~+150	°C

Electrical Characteristics at $T_j=25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{\text{GS}}=0\text{V}$, $I_{\text{D}}=250\mu\text{A}$	30	---	---	V
$\Delta \text{BV}_{\text{DSS}}/\Delta T_j$	BVDSS Temperature Coefficient	Reference to 25°C , $I_{\text{D}}=1\text{mA}$	---	0.021	---	$\text{V}/^\circ\text{C}$
$R_{\text{DS}(\text{ON})}$	Static Drain-Source On-Resistance ²	$V_{\text{GS}}=10\text{V}$, $I_{\text{D}}=5\text{A}$	---	24	28	$\text{m}\Omega$
		$V_{\text{GS}}=4.5\text{V}$, $I_{\text{D}}=4\text{A}$	---	34	40	
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$V_{\text{GS}}=V_{\text{DS}}$, $I_{\text{D}}=250\mu\text{A}$	0.9	1.2	2.5	V
$\Delta V_{\text{GS}(\text{th})}$	$V_{\text{GS}(\text{th})}$ Temperature Coefficient		---	-5	---	$\text{mV}/^\circ\text{C}$
I_{DSS}	Drain-Source Leakage Current	$V_{\text{DS}}=24\text{V}$, $V_{\text{GS}}=0\text{V}$, $T_j=25^\circ\text{C}$	---	---	1	uA
		$V_{\text{DS}}=24\text{V}$, $V_{\text{GS}}=0\text{V}$, $T_j=55^\circ\text{C}$	---	---	5	
I_{GSS}	Gate-Source Leakage Current	$V_{\text{GS}}=\pm 20\text{V}$, $V_{\text{DS}}=0\text{V}$	---	---	± 100	nA
g_{fs}	Forward Transconductance	$V_{\text{DS}}=5\text{V}$, $I_{\text{D}}=5\text{A}$	---	7	---	S
R_g	Gate Resistance	$V_{\text{DS}}=0\text{V}$, $V_{\text{GS}}=0\text{V}$, $f=1\text{MHz}$	---	2.5	5	Ω
Q_g	Total Gate Charge (4.5V)	$V_{\text{DS}}=15\text{V}$, $V_{\text{GS}}=4.5\text{V}$, $I_{\text{D}}=5\text{A}$	---	6	8.4	nC
Q_{gs}	Gate-Source Charge		---	2.5	3.5	
Q_{gd}	Gate-Drain Charge		---	2.1	2.9	
$T_{\text{d}(\text{on})}$	Turn-On Delay Time	$V_{\text{DD}}=15\text{V}$, $V_{\text{GS}}=10\text{V}$, $R_g=3.3$ $I_{\text{D}}=5\text{A}$	---	2.4	4.8	ns
T_r	Rise Time		---	7.8	14	
$T_{\text{d}(\text{off})}$	Turn-Off Delay Time		---	22	44	
T_f	Fall Time		---	4	8	
C_{iss}	Input Capacitance	$V_{\text{DS}}=15\text{V}$, $V_{\text{GS}}=0\text{V}$, $f=1\text{MHz}$	---	572	800	pF
C_{oss}	Output Capacitance		---	81	112	
C_{rss}	Reverse Transfer Capacitance		---	65	91	
I_s	Continuous Source Current ^{1,4}	$V_G=V_D=0\text{V}$, Force Current	---	---	5.8	A
I_{SM}	Pulsed Source Current ^{2,4}		---	---	30	A
V_{SD}	Diode Forward Voltage ²	$V_{\text{GS}}=0\text{V}$, $I_s=3\text{A}$, $T_j=25^\circ\text{C}$	---	---	1.2	V
t_{rr}	Reverse Recovery Time	$I_F=5\text{A}$, $dI/dt=100\text{A}/\mu\text{s}$ $T_j=25^\circ\text{C}$	---	19	---	nS
Q_{rr}	Reverse Recovery Charge		---	1.04	---	nC

**Fig.1 Typical Output Characteristics****Fig.2 On-Resistance vs. G-S Voltage****Fig.3 Forward Characteristics Of Reverse****Fig.4 Gate-Charge Characteristics****Fig.5 Normalized $V_{GS(th)}$ vs. T_J** **Fig.6 Normalized $R_{DS(on)}$ vs. T_J**





Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.400	1.600	0.055	0.063
b	0.350	0.520	0.013	0.197
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550 REF		0.061 REF	
E	2.350	2.550	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500 TYP		0.060TYP	
e1	3.000 TYP		0.118TYP	
L	0.900	1.100	0.035	0.047